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Signature

PTO/SB/21 (08-00)
Approved for use through 10/31/2002, OMB 0651-0031
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TRANSMITTAL FORM (to be used for all correspondence after initial filing)			Application No.	09/517,705					
			Filing Date	March 2, 2000					
			First Named Inventor	Chunlin Liang					
			Group Art Unit	2811					
			Examiner Name	Steven Ho Yin Loke					
Total Number of Pages in This Submission 10			Attorney Docket Number	42390P5771D					
ENCLOSURES (check all that apply)									
Fee Transmittal	Form	Assignmen (for an App		After Allowance Communication to Group					
Fee Attac	hed	Drawing(s))	Appeal Communication to Board of Appeals and Interferences					
Amendment / Re	esponse	Licensing-r	elated Papers	Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)					
After Fina	al /declaration(s)	Petition		Proprietary Information					
Extension of Tim	ne Request	Petition to C Provisional	Convert a Application	Status Letter					
Express Abandonment Request		Power of A Change of	ttorney, Revocation Correspondence Address	Other Enclosure(s) (please identify below): Return Postcard					
Information Disclosure Statement		Terminal D	Disclaimer						
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Certified Copy of Priority Document(s)		CD, Numbe	er of CD(s)						
Response to Missing Parts/ Incomplete Application		Remarks							
Basic Filing Fee				280					
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Response Parts und 1.52 or 1.5	e to Missing ler 37 CFR 53								
	SIGNATUR	E OF APPLICA	NT, ATTORNEY, OR AG	ENT					
Firm or	Raul D. Martir	nez, Reg. No.	46,904						
Individual name	BLAKELY, S	SOKOLOFF,	TAYLOR & ZAFM	IAN LLP					
Signature	RaulD	Hot							
Date	April 28, 200	3							
	CERTIF	ICATE OF MAIL	ING/TRANSMISSION						
I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class mail with sufficient postage in an envelope addressed to: Box Non-Fee Amendment, Assistant Commissioner for Patents, Washington, D.C. 20231 on: April 28, 2003									
Typed or printed name Littian E. Rodriguez)									

Date

April 28, 2003

PTO/SB/17 (01-03)

Approved for use through 04/30/2003. OMB 0551-0032

U.S. Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE

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TRANSMITTAL for FY 2003

Effective 01/01/2003. Patent fees are subject to annual revision.

Applicant claims small entity status. See 37 CFR 1.27.

TOTAL AMOUNT OF PAYMENT

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Complete if Known					
Application Number	09/517,705				
Filing Date	March 2, 2000				
First Named Inventor	Chunlin Liang				
Examiner Name	Steven Ho Yin Loke				
Group/Art Unit	2811				
Attorney Docket No.	42390P5771D				

METHOD OF PAYMENT (check one)		FEE CALCULATION (continued)						
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Name Blakely, Sokoloff, Taylor & Zafman LLP	2053	130	2053	130	Non-English specification	n		
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Charge any additional fee(s) required under 37 CFR §§ 1.16, 1.17, 1.18 and 1.20.	1806	1,840 *	1805	1,840 '	* Requesting publication	of SIR after		
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to the above-identified deposit account	1251	110	2251	55	Extension for reply with	in first month		
FEE CALCULATION	1252	410	2252	205	Extension for reply with			
1. BASIC FILING FEE	1253	930	2253	465	Extension for reply with			
Large Entity Small Entity Fee Fee Fee Fee Description Fee Paid	1254	1,450	2254	725	Extension for reply with			
Code (\$) Code (\$)	1255	1,970	2255	985	Extension for reply with	in fifth month		
1001 750 2001 375 Utility filing fee	1404	320	2401	160	Notice of Appeal			
1002 330 2002 165 Design filing fee	1402	320	2402	160	Filing a brief in support			
1003 520 2003 260 Plant filing fee	1403	280	2403	140	Request for oral hearing	-	Œ.	
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**or number previously paid, if greater, For Reissues, see below								
SUBMITTED BY	1 6	Octions.	on Ma			Comp	lete (if applica	ble)
Name (Print/Type) Raul D. Martinez		Registration No. (Attorney/Agent) 46,904 Telephone (310)			(310) 20	7-3800		
Signature Raul DMat						Date	04/28	8/03



Our Ref. No.: 42390P5771D

Examiner: Steven Ho Yin Loke

Art Unit: 2811

Ameth 51818

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Chunlin Liang, et al.

Application No.: 09/517,705

Filed: March 2, 2000

For: COMPLEMENTARY METAL GATE

ELECTRODE TECHNOLOGY

Box Non-Fee Amendment Assistant Commissioner for Patents Washington, D.C. 20231 RECEIVED

AMENDMENT AND RESPONSE TO OFFICE ACTION

In response to the Office Action dated February 27, 2003, Applicants respectfully request entry of the amendments set forth below and consideration of the remarks that follow.

IN THE CLAIMS

Please substitute the following amended claims for the pending claims with the same numbers:

1. (Four Times Amended) A circuit device comprising:

a first transistor including a first metal gate electrode over a first gate dielectric on a first area of a semiconductor substrate and having a work function corresponding to the work function of one of P-type silicon and N-type silicon;

a second transistor complementary to the first transistor including a second metal gate electrode over a second gate dielectric on a second different area of a semiconductor substrate and having a work function corresponding to the work function of the other one of P-type silicon and N-type silicon; and